

Vishay High Power Products

Medium Power Thyristors (Stud Version), 16 A



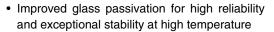
TO-208AA (TO-48)

16 A

PRODUCT SUMMARY

 $I_{T(AV)}$

FEATURES





- · High dl/dt and dV/dt capabilities
- · Standard package
- · Low thermal resistance
- · Metric threads version available
- Types up to 1200 V V_{DRM}/V_{RRM}
- · RoHS compliant
- Designed and qualified for industrial and consumer level

TYPICAL APPLICATIONS

- · Medium power switching
- Phase control applications
- · Can be supplied to meet stringent military, aerospace and other high reliability requirements

MAJOR RATINGS AND CHARACTERISTICS					
PARAMETER	TEST CONDITIONS	VALUES	UNITS		
		16	Α		
I _{T(AV)}	T _C	85	°C		
I _{T(RMS)}		35	A		
I _{TSM}	50 Hz	340	A		
	60 Hz	360	A		
l ² t	50 Hz	574	A ² s		
	60 Hz	524	A-S		
V _{DRM} /V _{RRM}		100 to 1200	V		
tq	Typical	110	μs		
T _J		- 65 to 125	°C		

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16RIA Series

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ELECTRICAL SPECIFICATIONS

VOLTAGI	VOLTAGE RATINGS							
TYPE NUMBER	VOLTAGE CODE			I_{DRM}/I_{RRM} MAXIMUM AT $T_J = T_J$ MAXIMUM mA				
	10	100	150	20				
	20	200	300					
	40	400	500					
16RIA	60	600	700	10				
	80	800	900	10				
	100	1000	1100					
	120	1200	1300					

Notes

 $[\]ensuremath{^{(2)}}$ For voltage pulses with $t_p \leq 5 \ ms$

PARAMETER	SYMBOL	TEST CONDITIONS			VALUES	UNITS
Maximum average on-state current	,	180° sinusoidal conduction		16	Α	
at case temperature	I _{T(AV)}	180° Siriuso	idal conduction		85	°C
Maximum RMS on-state current	I _{T(RMS)}				35	Α
		t = 10 ms	No voltage		340	
Maximum peak, one-cycle		t = 8.3 ms	reapplied		360	٨
non-repetitive surge current	I _{TSM}	t = 10 ms	100 % V _{RRM}	Sinusoidal	285	А
		t = 8.3 ms	reapplied	half wave,	300	
Maximum I ² t for fusing		t = 10 ms	No voltage	initial T _J =	574	
	l ² t	t = 8.3 ms reapplied	T _J maximum	524	A ² s	
		t = 10 ms	100 % V _{RRM}		405	A-S
		t = 8.3 ms	reapplied		375	
Maximum I ² √t for fusing	I²√t	t = 0.1 to 10 ms, no voltage reapplied, $T_J = T_J$ maximum		5740	A²√s	
Low level value of threshold voltage	V _{T(TO)1}		(16.7 % x π x $I_{T(AV)} < I < \pi$ x $I_{T(AV)}$), $I_{J} = I_{J}$ maximum		0.97	V
High level value of threshold voltage	V _{T(TO)2}	$(I > \pi \times I_{T(A)})$	(1) , $T_J = T_J$ maxim	num	1.24	
Low level value of on-state slope resistance	r _{t1}	(16.7 % x π x $I_{T(AV)} < I < \pi$ x $I_{T(AV)}$), $I_{J} = I_{J}$ maximum			17.9	mΩ
High level value of on-state slope resistance	r _{t2}	$(I > \pi \times I_{T(AV)}), T_J = T_J \text{ maximum}$		13.6	1117.5	
Maximum on-state voltage	V _{TM}	I _{pk} = 50 A, T _J = 25 °C		1.75	V	
Maximum holding current	I _H	T 05 00	anada ayanlı C.	/ registive lead	130	nn A
Latching current	ΙL	T _J = 25 °C, anode supply 6 V, resistive load		mA		

 $^{^{(1)}}$ Units may be broken over non-repetitively in the off-state direction without damage, if dl/dt does not exceed 20 A/ μ s



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SWITCHING					
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS
V _{DRM} ≤ 600 V				200	
Maximum rate of rise	$V_{DRM} \le 800 \text{ V}$	dl/dt	$T_J = T_J$ maximum, $V_{DM} = Rated V_{DRM}$	180	A/μs
of turned-on current	V _{DRM} ≤ 1000 V	ui/ut	Gate pulse = 20 V, 15 Ω , t_p = 6 μ s, t_r = 0.1 μ s maximum I_{TM} = (2 x rated dl/dt) A	160	
	V _{DRM} ≤ 1600 V			150	
Typical turn-on time		t _{gt}	$T_J = 25 ^{\circ}\text{C}$, at rated V_{DRM}/V_{RRM} , $T_J = 125 ^{\circ}\text{C}$	0.9	
Typical reverse recovery time		t _{rr}	$T_J = T_J$ maximum, $I_{TM} = I_{T(AV)}$, $t_p > 200 \ \mu s$, $dI/dt = -10 \ A/\mu s$	4	μs
Typical turn-off time t _q		tq	$T_J = T_J \ maximum, \ I_{TM} = I_{T(AV)}, \ t_p > 200 \ \mu s, \ V_R = 100 \ V,$ $dI/dt = \text{- 10 A/}\mu s, \ dV/dt = 20 \ V/\mu s \ linear \ to \ 67 \ \% \ V_{DRM},$ gate bias 0 V to 100 W	110	

Note

⁻ t_q = 10 μs up to 600 V, t_q = 30 μs up to 1600 V available on special request

BLOCKING					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum critical rate of rise	dV/dt	$T_J = T_J$ maximum linear to 100 % rated V_{DRM}	100	V/µs	
of off-state voltage	uv/ut	$T_J = T_J$ maximum linear to 67 % rated V_{DRM}	300 (1)	ν/μ5	

Note

 $^{^{(1)}}$ Available with: dV/dt = 1000 V/ μ s, to complete code add S90 i.e. 16RIA120S90

TRIGGERING						
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS	
Maximum peak gate power	P _{GM}	T T		8.0	W	
Maximum average gate power	$P_{G(AV)}$	- IJ = IJ Maximum	$T_J = T_J$ maximum			
Maximum peak positive gate current	I _{GM}	$T_J = T_J$ maximum		1.5	Α	
Maximum peak negative gate voltage	-V _{GM}	$T_J = T_J$ maximum		10	V	
DC gate current required to trigger		T _J = - 65 °C	Maximum required gate trigger	90		
	I _{GT}	T _J = 25 °C	current/voltage are the lowest value which will trigger all units 6 V anode to cathode applied	60	mA	
		T _J = 125 °C		35		
	V _{GT}	T _J = - 65 °C		3.0		
DC gate voltage required to trigger		T _J = 25 °C		2.0	V	
		T _J = 125 °C		1.0		
DC gate current not to trigger	DC gate current not to trigger I_{GD} $T_J = T_J$ maximum, V_{DRM} = Rated value		2.0	mA		
DC gate voltage not to trigger	V _{GD}	$T_J = T_J \text{maximum}, \\ V_{DRM} = \text{Rated value} \\ \\ N_{DRM} = Rated$		0.2	>	

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THERMAL AND MECHANICAL SPECIFICATIONS						
PARAMETER SYMBOL		TEST CONDITIONS	VAL	.UES	UNITS	
Maximum operating junction and storage temperature range	T _J , T _{Stg}		- 65 t	o 125	ů	
Maximum thermal resistance, junction to case	R _{thJC}	DC operation	0.86		K/W	
Maximum thermal resistance, case to heatsink	R _{thCS}	Mounting surface, smooth, flat and greased		0.35		
			TO NUT	TO DEVICE		
		Later and the second	20 (27.5)	25	lbf ⋅ in	
Mounting torque		Lubricated threads (Non-lubricated threads)	0.23 (0.32)	0.29	kgf · m	
		(Non labilitation timeday)	2.3 (3.1)	2.8	N·m	
Approximate weight			1	4	g	
			0.49		OZ.	
Case style		See dimensions - link at the end of datasheet	TO-	208AA (TO-48)	

△R _{thJC} CONDUCTION							
CONDUCTION ANGLE	SINUSOIDAL CONDUCTION	RECTANGULAR CONDUCTION	TEST CONDITIONS	UNITS			
180°	0.21	0.15					
120°	0.25	0.25					
90°	0.31	0.34	$T_J = T_J \text{ maximum}$	K/W			
60°	0.45	0.47					
30°	0.76	0.76					

Note

[•] The table above shows the increment of thermal resistance RthJC when devices operate at different conduction angles than DC

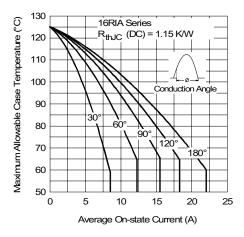


Fig. 1 - Current Ratings Characteristics

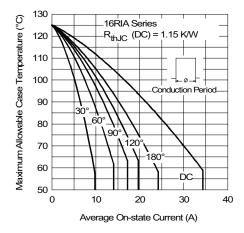


Fig. 2 - Current Ratings Characteristics



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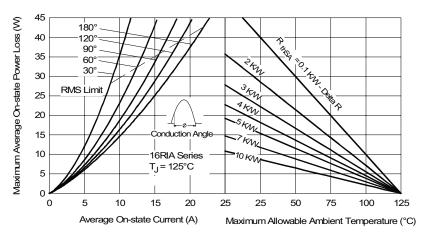


Fig. 3 - On-State Power Loss Characteristics

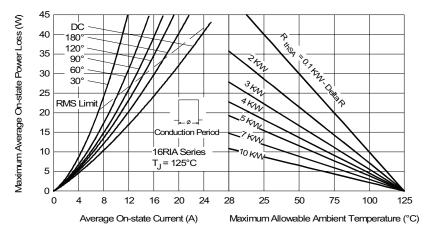


Fig. 4 - On-State Power Loss Characteristics

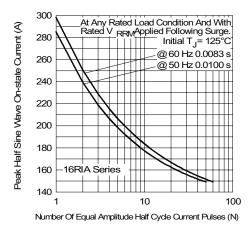


Fig. 5 - Maximum Non-Repetitive Surge Current

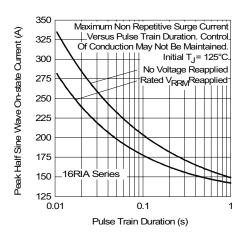


Fig. 6 - Maximum Non-Repetitive Surge Current

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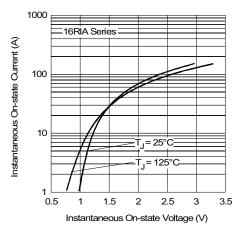


Fig. 7 - Forward Voltage Drop Characteristics

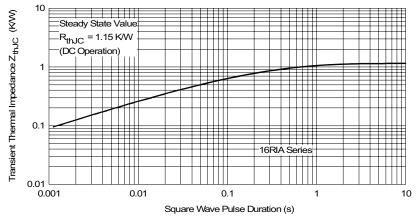


Fig. 8 - Thermal Impedance Z_{thJC} Characteristics

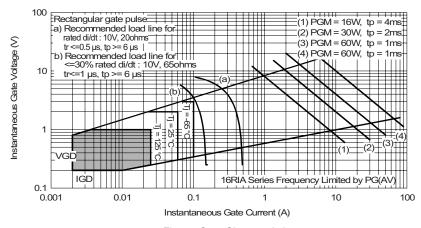


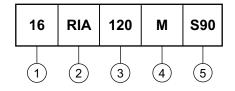
Fig. 9 - Gate Characteristics



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ORDERING INFORMATION TABLE

Device code



- 1 Current code
- Essential part number
- Voltage code x 10 = V_{RRM} (see Voltage Ratings table)
- None = Stud base TO-208AA (TO-48) 1/4" 28UNF-2A
 M = Stud base TO-208AA (TO-48) M6 x 1
- 5 Critical dV/dt:
 None = 300 V/µs (standard value)
 S90 = 1000 V/µs (special selection)

LINKS TO RELATED DOCUMENTS			
Dimensions	http://www.vishay.com/doc?95333		

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